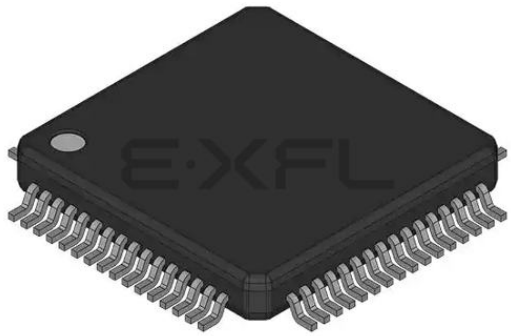

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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	S08
Core Size	8-Bit
Speed	20MHz
Connectivity	I²C, LINbus, SPI, UART/USART
Peripherals	LVD, POR, PWM, WDT
Number of I/O	57
Program Memory Size	60KB (60K x 8)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 16x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-QFP
Supplier Device Package	64-QFP (14x14)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mc9s08pa60vqh

- Input/Output
  - 57 GPIOs including one output-only pin
  - Two 8-bit keyboard interrupt modules (KBI)
  - Two true open-drain output pins
  - Eight, ultra-high current sink pins supporting 20 mA source/sink current
- Package options
  - 64-pin LQFP; 64-pin QFP
  - 48-pin LQFP
  - 44-pin LQFP
  - 32-pin LQFP

Table of Contents

Symbol	Description	Min.	Max.	Unit
V_{AIO}	Analog[1], $\overline{\text{RESET}}$, EXTAL, and XTAL input voltage	–0.3	V_{DD} + 0.3	V
I_D	Instantaneous maximum current single pin limit (applies to all port pins)	–25	25	mA
V_{DDA}	Analog supply voltage	V_{DD} – 0.3	V_{DD} + 0.3	V

1. Analog pins are defined as pins that do not have an associated general purpose I/O port function.

5 General

5.1 Nonswitching electrical specifications

5.1.1 DC characteristics

This section includes information about power supply requirements and I/O pin characteristics.

Table 2. DC characteristics

Symbol	C	Descriptions			Min	Typical[1]	Max	Unit
—	—	Operating voltage		—	2.7	—	5.5	V
V_{OH}	P	Output high voltage	All I/O pins, low-drive strength	5 V, I_{load} = -2 mA	V_{DD} - 1.5	—	—	V
	C			3 V, I_{load} = -0.6 mA	V_{DD} - 0.8	—	—	V
	P		High current drive pins, high-drive strength	5 V, I_{load} = -20 mA	V_{DD} - 1.5	—	—	V
	C			3 V, I_{load} = -6 mA	V_{DD} - 0.8	—	—	V
I_{OHT}	D	Output high current	Max total I_{OH} for all ports	5 V	—	—	-100	mA
				3 V	—	—	-60	
V_{OL}	P	Output low voltage	All I/O pins, low-drive strength	5 V, I_{load} = 2 mA	—	—	1.5	V
	C			3 V, I_{load} = 0.6 mA	—	—	0.8	V
	P		High current drive pins, high-drive strength[2]	5 V, I_{load} =20 mA	—	—	1.5	V
	C			3 V, I_{load} = 6 mA	—	—	0.8	V
I_{OLT}	D	Output low current	Max total I_{OL} for all ports	5 V	—	—	100	mA
				3 V	—	—	60	

Table continues on the next page...

Table 2. DC characteristics (continued)

Symbol	C	Descriptions			Min	Typical[1]	Max	Unit
V_{IH}	P	Input high voltage	All digital inputs	V_{DD}>4.1V	0.70 × V_{DD}	—	—	V
				V_{DD}>2.7V	0.85 × V_{DD}	—	—	
V_{IL}	P	Input low voltage	All digital inputs	V_{DD}>4.1V	—	—	0.35 × V_{DD}	V
				V_{DD}>2.7V	—	—	0.30 × V_{DD}	
V_{hys}	C	Input hysteresis	All digital inputs	—	0.06 × V_{DD}	—	—	mV
$\lvert I_{In}\rvert$	P	Input leakage current	All input only pins (per pin)	V_{IN} = V_{DD} or V_{SS}	—	0.1	1	µA
$\lvert I_{OZ}\rvert$	P	Hi-Z (off-state) leakage current	All input/output (per pin)	V_{IN} = V_{DD} or V_{SS}	—	0.1	1	µA
$\lvert I_{OZTOT}\rvert$	C	Total leakage combined for all inputs and Hi-Z pins	All input only and I/O	V_{IN} = V_{DD} or V_{SS}	—	—	2	µA
R_{PU}	P	Pullup resistors	All digital inputs, when enabled (all I/O pins other than PTA5/ IRQ/TCLK/RESET	—	17.5	—	52.5	kΩ
R_{PU}[3]	P	Pullup resistors	PTA5/IRQ/TCLK/ RESET	—	17.5	—	52.5	kΩ
I_{IC}	D	DC injection current[4, 5, 6]	Single pin limit	V_{IN} < V_{SS}, V_{IN} > V_{DD}	-0.2	—	2	mA
			Total MCU limit, includes sum of all stressed pins		-5	—	25	
C_{In}	C	Input capacitance, all pins		—	—	—	8	pF
V_{RAM}	C	RAM retention voltage		—	2.0	—	—	V

1. Typical values are measured at 25 °C. Characterized, not tested.
2. Only PTB4, PTB5, PTD0, PTD1, PTE0, PTE1, PTH0, and PTH1 support ultra high current output.
3. The specified resistor value is the actual value internal to the device. The pullup value may appear higher when measured externally on the pin.
4. All functional non-supply pins, except for PTA5, are internally clamped to V_{SS} and V_{DD}.
5. Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the large one.
6. Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If the positive injection current (V_{In} > V_{DD}) is higher than I_{DD}, the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure that external V_{DD} load will shunt current higher than maximum injection current when the MCU is not consuming power, such as no system clock is present, or clock rate is very low (which would reduce overall power consumption).

Table 3. LVD and POR Specification

Symbol	C	Description	Min	Typ	Max	Unit
V_{POR}	D	POR re-arm voltage[1]	1.5	1.75	2.0	V
V_{LVDH}	C	Falling low-voltage detect threshold - high range (LVDV = 1)[2]	4.2	4.3	4.4	V

Table continues on the next page...

5.1.2 Supply current characteristics

This section includes information about power supply current in various operating modes.

Table 4. Supply current characteristics

Num	C	Parameter	Symbol	Bus Freq	V_{DD} (V)	Typical[1]	Max	Unit	Temp
1	C	Run supply current FEI mode, all modules on; run from flash	RI_{DD}	20 MHz	5	12.6	—	mA	-40 to 105 °C
	C			10 MHz		7.2	—		
				1 MHz		2.4	—		
	C			20 MHz	3	9.6	—		
	C			10 MHz		6.1	—		
				1 MHz		2.1	—		
2	C	Run supply current FEI mode, all modules off & gated; run from flash	RI_{DD}	20 MHz	5	10.5	—	mA	-40 to 105 °C
	C			10 MHz		6.2	—		
				1 MHz		2.3	—		
	C			20 MHz	3	7.4	—		
	C			10 MHz		5.0	—		
				1 MHz		2.0	—		
3	P	Run supply current FBE mode, all modules on; run from RAM	RI_{DD}	20 MHz	5	12.1	14.8	mA	-40 to 105 °C
	C			10 MHz		6.5	—		
				1 MHz		1.8	—		
	P			20 MHz	3	9.1	11.8		
	C			10 MHz		5.5	—		
				1 MHz		1.5	—		
4	P	Run supply current FBE mode, all modules off & gated; run from RAM	RI_{DD}	20 MHz	5	9.8	12.3	mA	-40 to 105 °C
	C			10 MHz		5.4	—		
				1 MHz		1.6	—		
	P			20 MHz	3	6.9	9.2		
	C			10 MHz		4.4	—		
				1 MHz		1.4	—		
5	C	Wait mode current FEI mode, all modules on	WI_{DD}	20 MHz	5	7.8	—	mA	-40 to 105 °C
	C			10 MHz		4.5	—		
				1 MHz		1.3	—		
	C			20 MHz	3	5.1	—		
				10 MHz		3.5	—		
				1 MHz		1.2	—		
6	C	Stop3 mode supply current no clocks active (except 1 kHz LPO clock)[2, 3]	$S3I_{DD}$	—	5	3.8	—	µA	-40 to 105 °C
	C			—	3	3	—		-40 to 105 °C

Table continues on the next page...

Table 4. Supply current characteristics (continued)

Num	C	Parameter	Symbol	Bus Freq	V_{DD} (V)	Typical[1]	Max	Unit	Temp
7	C	ADC adder to stop3	—	—	5	44	—	µA	-40 to 105 °C
	C	ADLPC = 1 ADLSMP = 1 ADCO = 1 MODE = 10B ADICLK = 11B			3	40	—		
8	C	LVD adder to stop3[4]	—	—	5	130	—	µA	-40 to 105 °C
	C				3	125	—		

1. Data in Typical column was characterized at 5.0 V, 25 °C or is typical recommended value.
2. RTC adder cause <1 µA I_{DD} increase typically, RTC clock source is 1 kHz LPO clock.
3. ACMP adder cause <1 µA I_{DD} increase typically.
4. LVD is periodically woken up from stop3 by 5% duty cycle. The period is equal to or less than 2 ms.

5.1.3 EMC performance

Electromagnetic compatibility (EMC) performance is highly dependant on the environment in which the MCU resides. Board design and layout, circuit topology choices, location and characteristics of external components as well as MCU software operation all play a significant role in EMC performance. The system designer should consult Freescale applications notes such as AN2321, AN1050, AN1263, AN2764, and AN1259 for advice and guidance specifically targeted at optimizing EMC performance.

5.2 Switching specifications

5.2.1 Control timing

Table 5. Control timing

Num	C	Rating	Symbol	Min	Typical[1]	Max	Unit
1	P	Bus frequency (t_{cyc} = 1/f_{Bus})	f_{Bus}	DC	—	20	MHz
2	P	Internal low power oscillator frequency	f_{LPO}	0.67	1.0	1.25	KHz
3	D	External reset pulse width	t_{extrst}	1.5 × t_{Self_reset}	—	—	ns
4	D	Reset low drive	t_{rstdrv}	34 × t_{cyc}	—	—	ns
5	D	BKGD/MS setup time after issuing background debug force reset to enter user or BDM modes	t_{MSSU}	500	—	—	ns
6	D	BKGD/MS hold time after issuing background debug force reset to enter user or BDM modes[3]	t_{MSH}	100	—	—	ns

Table continues on the next page...

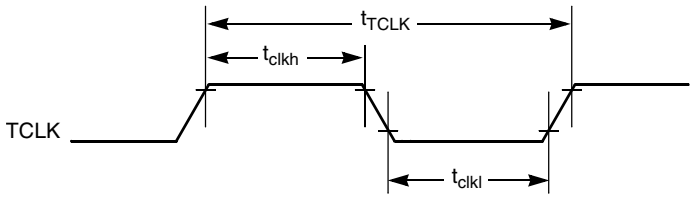


Figure 9. Timer external clock

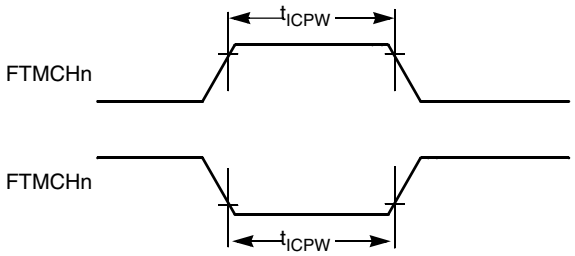


Figure 10. Timer input capture pulse

5.3 Thermal specifications

5.3.1 Thermal characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take $P_{I/O}$ into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} will be very small.

Table 8. Thermal characteristics

Rating	Symbol	Value	Unit
Operating temperature range (packaged)	T_A	-40 to 105	°C
Junction temperature range	T_J	-40 to 150	°C
Thermal resistance single-layer board			
64-pin LQFP	θ_{JA}	71	°C/W
64-pin QFP	θ_{JA}	61	°C/W
48-pin LQFP	θ_{JA}	81	°C/W
44-pin LQFP	θ_{JA}	75	°C/W
32-pin LQFP	θ_{JA}	86	°C/W

Table continues on the next page...

Table 8. Thermal characteristics (continued)

Rating	Symbol	Value	Unit
Thermal resistance four-layer board			
64-pin LQFP	θ_{JA}	53	°C/W
64-pin QFP	θ_{JA}	47	°C/W
48-pin LQFP	θ_{JA}	57	°C/W
44-pin LQFP	θ_{JA}	53	°C/W
32-pin LQFP	θ_{JA}	57	°C/W

The average chip-junction temperature (T_J) in °C can be obtained from:

$T_J = T_A + (P_D \times \theta_{JA})$

Where:

T_A = Ambient temperature, °C

θ_{JA} = Package thermal resistance, junction-to-ambient, °C/W

$P_D = P_{int} + P_{I/O}$

$P_{int} = I_{DD} \times V_{DD}$, Watts - chip internal power

$P_{I/O}$ = Power dissipation on input and output pins - user determined

For most applications, $P_{I/O} << P_{int}$ and can be neglected. An approximate relationship between P_D and T_J (if $P_{I/O}$ is neglected) is:

$P_D = K \div (T_J + 273\ °C)$

Solving the equations above for K gives:

$K = P_D \times (T_A + 273\ °C) + \theta_{JA} \times (P_D)^2$

where K is a constant pertaining to the particular part. K can be determined by measuring P_D (at equilibrium) for an known T_A. Using this value of K, the values of P_D and T_J can be obtained by solving the above equations iteratively for any value of T_A.

6 Peripheral operating requirements and behaviors

Table 10. Flash characteristics (continued)

C	Characteristic	Symbol	Min[1]	Typical[2]	Max[3]	Unit[4]
D	NVM Bus frequency	f_{NVMBUS}	1	—	25	MHz
D	NVM Operating frequency	f_{NVMOP}	0.8	—	1.05	MHz
D	Erase Verify All Blocks	t_{VFYALL}	—	—	17030	t_{cyc}
D	Erase Verify Flash Block	t_{RD1BLK}	—	—	16977	t_{cyc}
D	Erase Verify EEPROM Block	t_{RD1BLK}	—	—	843	t_{cyc}
D	Erase Verify Flash Section	t_{RD1SEC}	—	—	517	t_{cyc}
D	Erase Verify EEPROM Section	$t_{DRD1SEC}$	0.10	0.10	0.11	ms
D	Read Once	t_{RDONCE}	—	—	455	t_{cyc}
D	Program Flash (2 word)	t_{PGM2}	0.12	0.12	0.14	ms
D	Program Flash (4 word)	t_{PGM4}	0.20	0.21	0.24	ms
D	Program Once	$t_{PGMONCE}$	0.20	0.21	0.24	ms
D	Program EEPROM (1 Byte)	t_{DPGM1}	0.02	0.02	0.02	ms
D	Program EEPROM (2 Byte)	t_{DPGM2}	0.17	0.18	0.20	ms
D	Erase All Blocks	t_{ERSALL}	96.01	100.78	125.80	ms
D	Erase Flash Block	t_{ERSBLK}	95.98	100.75	125.76	ms
D	Erase Flash Sector	t_{ERSPG}	19.10	20.05	25.05	ms
D	Erase EEPROM Sector	t_{DERSPG}	4.81	5.05	6.30	ms
D	Unsecure Flash	t_{UNSECU}	96.01	100.78	125.80	ms
D	Verify Backdoor Access Key	t_{VFYKEY}	—	—	469	t_{cyc}
D	Set User Margin Level	t_{MLOADU}	—	—	442	t_{cyc}
C	FLASH Program/erase endurance T_L to T_H = -40 °C to 105 °C	n_{FLPE}	10 k	100 k	—	Cycles
C	EEPROM Program/erase endurance TL to TH = -40 °C to 105 °C	n_{FLPE}	50 k	500 k	—	Cycles
C	Data retention at an average junction temperature of T_{Javg} = 85°C after up to 10,000 program/erase cycles	t_{D_ret}	15	100	—	years

1. Minimun times are based on maxmum f_{NVMOP} and maximum f_{NVMBUS}
2. Typical times are based on typical f_{NVMOP} and maximum f_{NVMBUS}
3. Maximum times are based on minimum f_{NVMOP} and maximum f_{NVMBUS}
4. t_{cyc} = 1 / f_{NVMBUS}

Program and erase operations do not require any special power sources other than the normal V_{DD} supply. For more detailed information about program/erase operations, see the Memory section.

6.3 Analog

6.3.1 ADC characteristics

Table 11. 5 V 12-bit ADC operating conditions

Characteristic	Conditions	Symb	Min	Typ[1]	Max	Unit	Comment
Supply voltage	Absolute	V_{DDA}	2.7	—	5.5	V	—
	Delta to V_{DD} (V_{DD}-V_{DDAD})	ΔV_{DDA}	-100	0	+100	mV	
Ground voltage	Delta to V_{SS} (V_{SS}-V_{SSA})[1]	ΔV_{SSA}	-100	0	+100	mV	
Input voltage		V_{ADIN}	V_{REFL}	—	V_{REFH}	V	
Input capacitance		C_{ADIN}	—	4.5	5.5	pF	
Input resistance		R_{ADIN}	—	3	5	kΩ	—
Analog source resistance	12-bit mode • f_{ADCK} > 4 MHz • f_{ADCK} < 4 MHz	R_{AS}	— —	— —	2 5	kΩ	External to MCU
	10-bit mode • f_{ADCK} > 4 MHz • f_{ADCK} < 4 MHz		— —	— —	5 10		
	8-bit mode (all valid f_{ADCK})		—	—	10		
ADC conversion clock frequency	High speed (ADLPC=0)	f_{ADCK}	0.4	—	8.0	MHz	—
	Low power (ADLPC=1)		0.4	—	4.0		

1. Typical values assume V_{DDA} = 5.0 V, Temp = 25°C, f_{ADCK}=1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
1. DC potential difference.

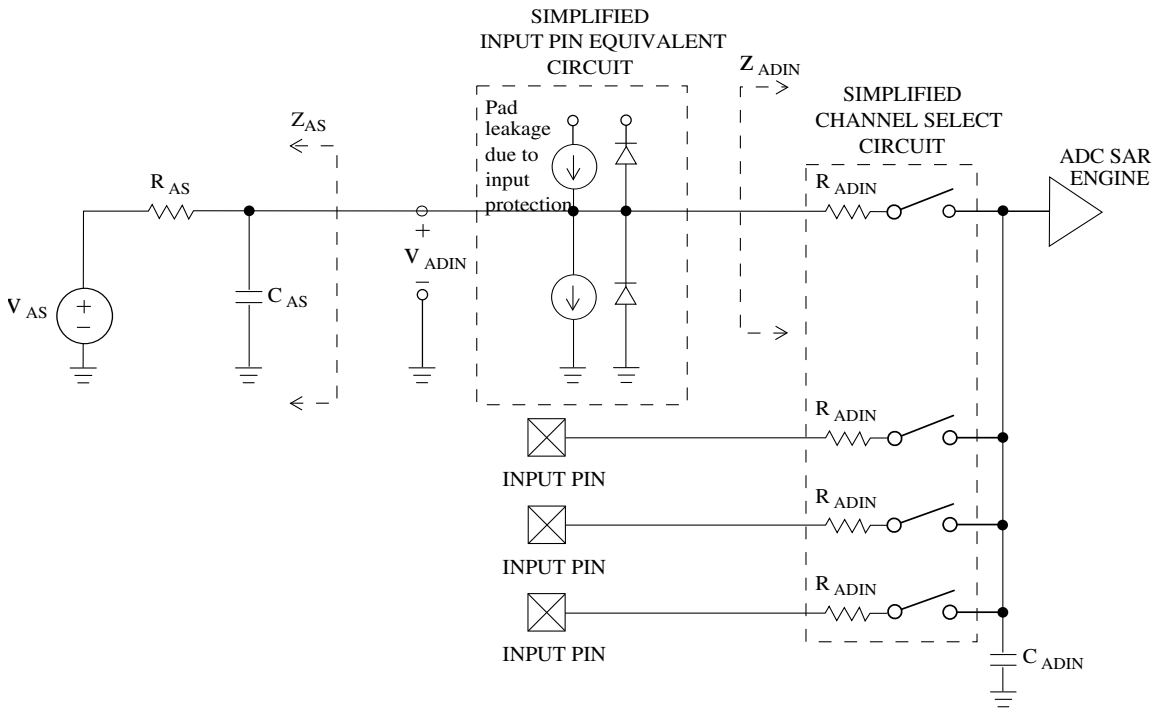


Figure 12. ADC input impedance equivalency diagram

Table 12. 12-bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

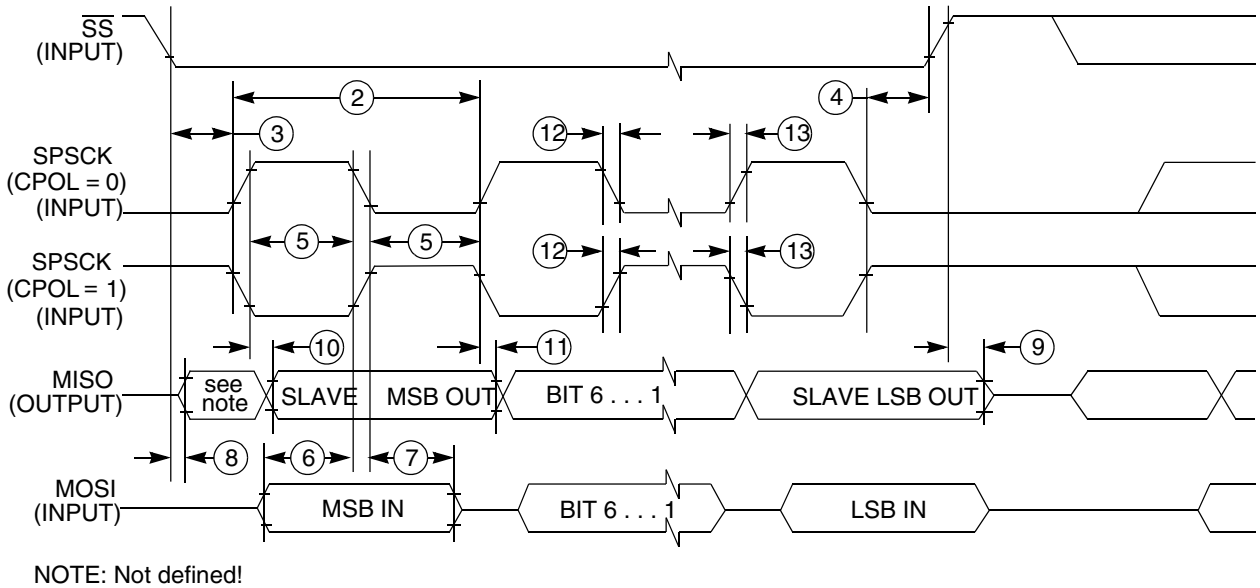
Characteristic	Conditions	C	Symb	Min	Typ[1]	Max	Unit
Supply current ADLPC = 1 ADLSMP = 1 ADCO = 1		T	I_{DDA}	—	133	—	µA
Supply current ADLPC = 1 ADLSMP = 0 ADCO = 1		T	I_{DDA}	—	218	—	µA
Supply current ADLPC = 0 ADLSMP = 1 ADCO = 1		T	I_{DDA}	—	327	—	µA
Supply current ADLPC = 0 ADLSMP = 0 ADCO = 1		T	I_{DDAD}	—	582	990	µA
Supply current	Stop, reset, module off	T	I_{DDA}	—	0.011	1	µA

Table continues on the next page...

Table 12. 12-bit ADC Characteristics (V_{REFH} = V_{DDA}, V_{REFL} = V_{SSA}) (continued)

Characteristic	Conditions	C	Symb	Min	Typ[1]	Max	Unit
ADC asynchronous clock source	High speed (ADLPC = 0)	P	f_{ADACK}	2	3.3	5	MHz
	Low power (ADLPC = 1)			1.25	2	3.3	
Conversion time (including sample time)	Short sample (ADLSMP = 0)	T	t_{ADC}	—	20	—	ADCK cycles
	Long sample (ADLSMP = 1)			—	40	—	
Sample time	Short sample (ADLSMP = 0)	T	t_{ADS}	—	3.5	—	ADCK cycles
	Long sample (ADLSMP = 1)			—	23.5	—	
Total unadjusted Error	12-bit mode	T	E_{TUE}	—	±5.0	—	LSB
	10-bit mode	P		—	±1.5	±2.0	
	8-bit mode	P		—	±0.7	±1.0	
Differential Non-Liniarity	12-bit mode	T	DNL	—	±1.0	—	LSB[2]
	10-bit mode	P		—	±0.25	±0.5	
	8-bit mode[3]	P		—	±0.15	±0.25	
Integral Non-Linearity	12-bit mode	T	INL	—	±1.0	—	LSB[2]
	10-bit mode	T		—	±0.3	±0.5	
	8-bit mode	T		—	±0.15	±0.25	
Zero-scale error	12-bit mode	C	E_{ZS}	—	±2.0	—	LSB[2]
	10-bit mode	P		—	±0.25	±1.0	
	8-bit mode	P		—	±0.65	±1.0	
Full-scale error[5]	12-bit mode	T	E_{FS}	—	±2.5	—	LSB[2]
	10-bit mode	T		—	±0.5	±1.0	
	8-bit mode	T		—	±0.5	±1.0	
Quantization error	≤12 bit modes	D	E_Q	—	—	±0.5	LSB[2]
Input leakage error[6]	all modes	D	E_{IL}	I_{In} * R_{AS}			mV
Temp sensor slope	-40°C– 25°C	D	m	—	3.266	—	mV/°C
	25°C– 125°C			—	3.638	—	
Temp sensor voltage	25°C	D	V_{TEMP25}	—	1.396	—	V

1. Typical values assume V_{DDA} = 5.0 V, Temp = 25°C, f_{ADCK}=1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
2. 1 LSB = (V_{REFH} - V_{REFL})/2^N
3. Monotonicity and no-missing-codes guaranteed in 10-bit and 8-bit modes
3. V_{ADIN} = V_{DDA}
4. I_{In} = leakage current (refer to DC characteristics)



NOTE: Not defined!

Figure 16. SPI slave mode timing (CPHA=1)

7 Dimensions

7.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to www.freescale.com and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
32-pin LQFP	98ASH70029A
44-pin LQFP	98ASS23225W
48-pin LQFP	98ASH00962A
64-pin QFP	98ASB42844B
64-pin LQFP	98ASS23234W

8 Pinout

8.1 Signal multiplexing and pin assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

Table 16. Pin availability by package pin-count

Pin Number				Lowest Priority <-- --> Highest				
64-LQFP 64-QFP	48-LQFP	44-LQFP	32-LQFP	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4
1	1	1	1	PTD1	KBI1P1	FTM2CH3	MOSI1	—
2	2	2	2	PTD0[1]	KBI1P0	FTM2CH2	SPSCK1	—
3	—	—	—	PTH7	—	—	—	—
4	—	—	—	PTH6	—	—	—	—
5	3	3	—	PTE7	—	TCLK2	—	—
6	4	4	—	PTH2	—	BUSOUT	—	—
7	5	5	3	—	—	—	—	V_{DD}
8	6	6	4	—	—	—	V_{DDA}	V_{REFH}
9	7	7	5	—	—	—	V_{SSA}	V_{REFL}
10	8	8	6	—	—	—	—	V_{SS}
11	9	9	7	PTB7	—	SCL	—	EXTAL
12	10	10	8	PTB6	—	SDA	—	XTAL
13	11	11	—	—	—	—	—	V_{SS}
14	—	—	—	PTH1[1]	—	FTM2CH1	—	—
15	—	—	—	PTH0[1]	—	FTM2CH0	—	—
16	12	—	—	PTE6	—	—	—	—
17	13	—	—	PTE5	—	—	—	—
18	14	12	9	PTB5[1]	FTM2CH5	SS0	—	—
19	15	13	10	PTB4[1]	FTM2CH4	MISO0	—	—
20	16	14	11	PTC3	FTM2CH3	—	ADP11	—
21	17	15	12	PTC2	FTM2CH2	—	ADP10	—
22	18	16	—	PTD7	KBI1P7	TXD2	—	—
23	19	17	—	PTD6	KBI1P6	RXD2	—	—
24	20	18	—	PTD5	KBI1P5	—	—	—
25	21	19	13	PTC1	—	FTM2CH1	ADP9	—
26	22	20	14	PTC0	—	FTM2CH0	ADP8	—
27	—	—	—	PTF7	—	—	ADP15	—

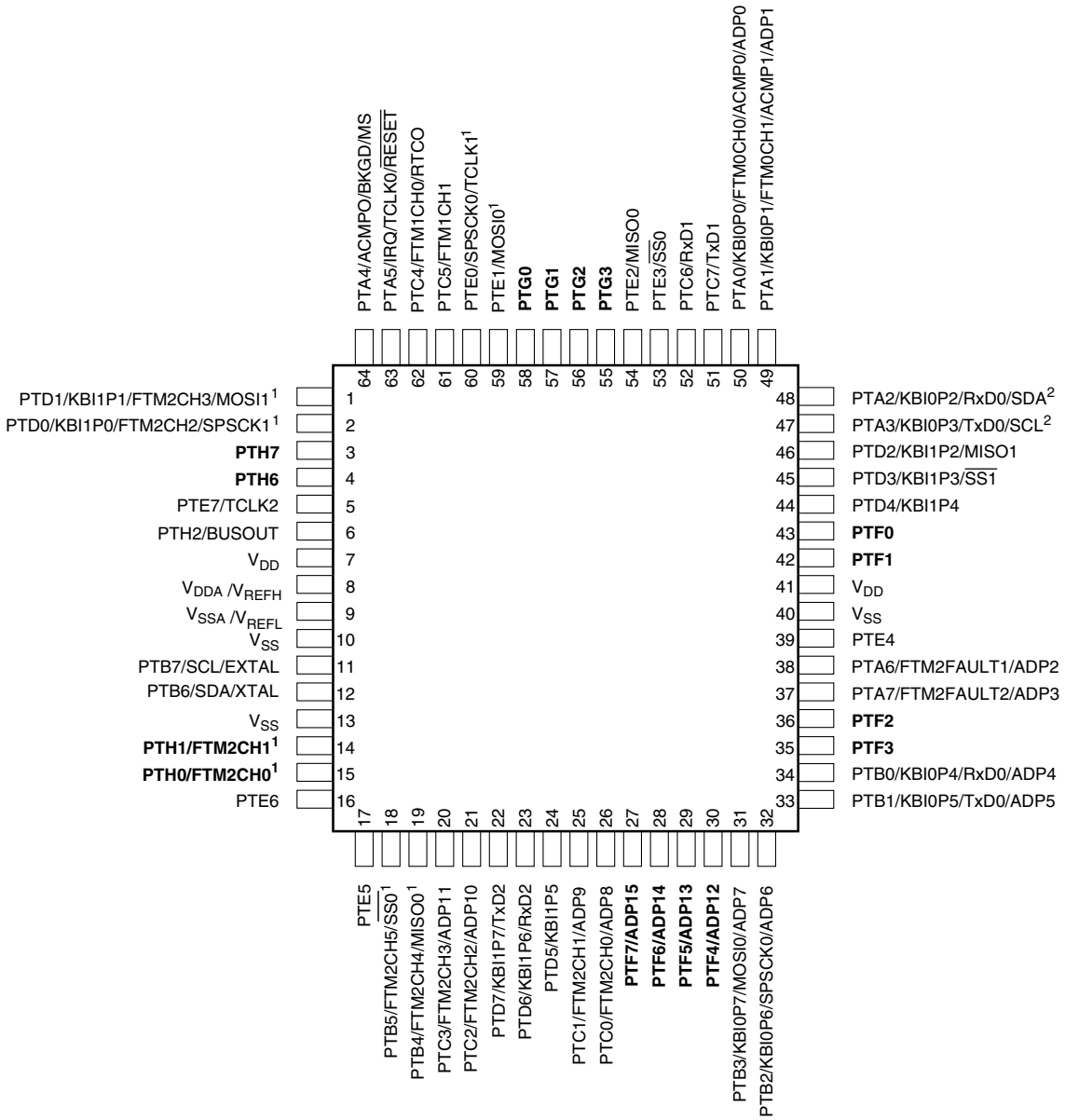
Table continues on the next page...

1. This is a high current drive pin when operated as output.
2. This is a true open-drain pin when operated as output.

Note

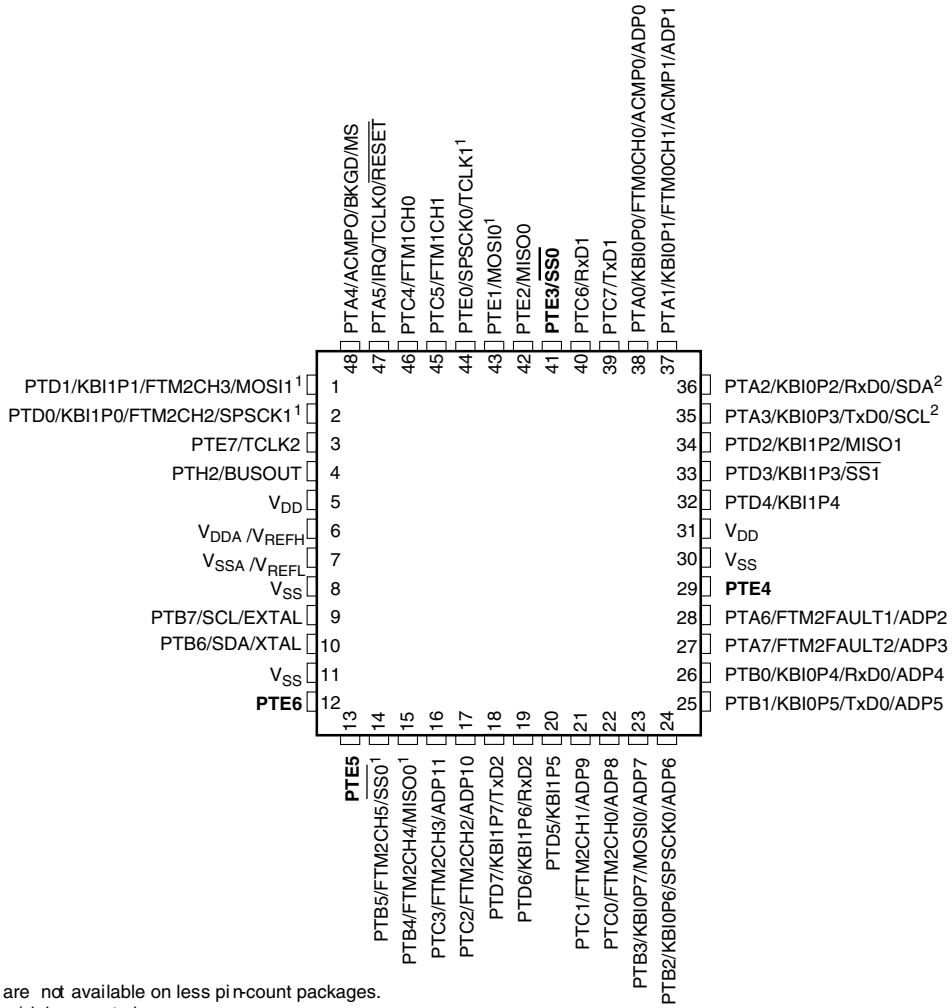
When an alternative function is first enabled, it is possible to get a spurious edge to the module. User software must clear any associated flags before interrupts are enabled. The table above illustrates the priority if multiple modules are enabled. The highest priority module will have control over the pin. Selecting a higher priority pin function with a lower priority function already enabled can cause spurious edges to the lower priority module. Disable all modules that share a pin before enabling another module.

8.2 Device pin assignment



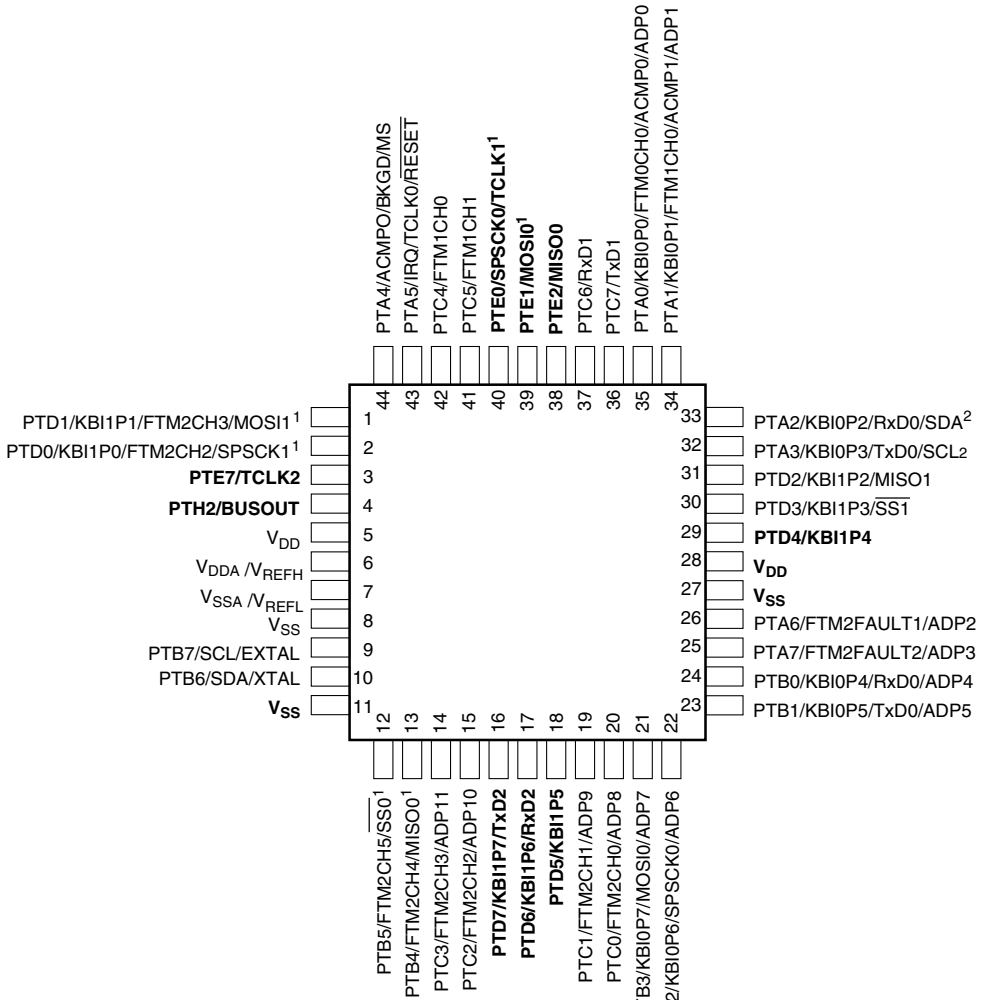
Pins in **bold** are not available on less pin-count packages.
1. High source/sink current pins
2. True open drain pins

Figure 17. MC9S08PA60 64-pin QFP and LQFP package



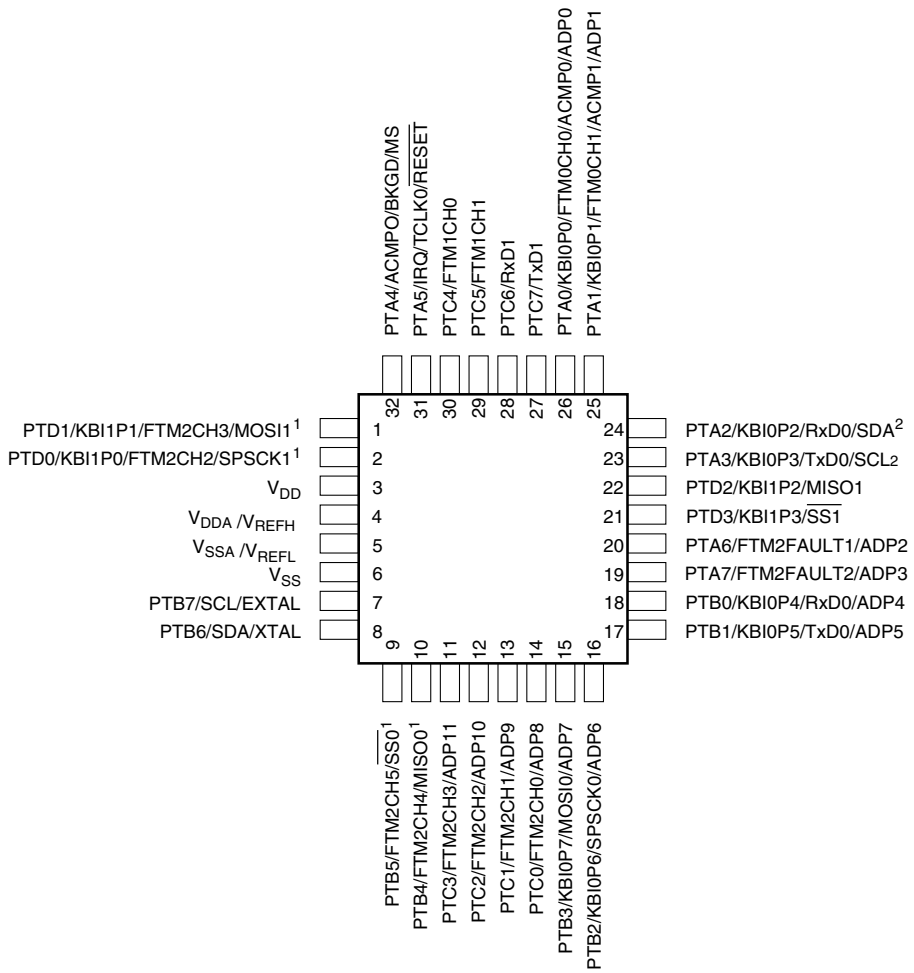
Pins in **bold** are not available on less pin-count packages.
1. High source/sink current pins
2. True open drain pins

Figure 18. MC9S08PA60 48-pin LQFP package



Pins in **bold** are not available on less pin-count packages.
1. High source/sink current pins
2. True open drain pins

Figure 19. MC9S08PA60 44-pin LQFP package



1. High source/sink current pins
2. True open drain pins

Figure 20. MC9S08PA60 32-pin LQFP package

9 Revision history

The following table provides a revision history for this document.

Table 17. Revision history

Rev. No.	Date	Substantial Changes
1	10/2012	Initial public release

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81829 Muenchen, Germany
+44 1296 380 456 (English)
+46 8 52200080 (English)
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Japan:
Freescale Semiconductor Japan Ltd.
Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku,
Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:
Freescale Semiconductor China Ltd.
Exchange Building 23F
No. 118 Jianguo Road
Chaoyang District
Beijing 100022
China
+86 10 5879 8000
support.asia@freescale.com

Document Number: MC9S08PA60
Rev. 1, 10/9/2012